

2SD2655

Silicon NPN Epitaxial Planer Low Frequency Power Amplifier

R07DS0281EJ0400 Rev.4.00 Jan 10, 2014

Features

• Small size package: MPAK (SC–59A)

• Large Maximum current: $I_C = 1 A$

• Low collector to emitter saturation voltage: $V_{\text{CE(sat)}} = 0.3 \text{ V max.} (\text{at } I_{\text{C}}/I_{\text{B}} = 0.5 \text{ A}/0.05 \text{ A})$

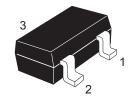
• High power dissipation: $P_C = 800 \text{ mW}$ (when using alumina ceramic board (25 x 60 x 0.7 mm))

• Complementary pair with 2SB1691

Outline

RENESAS Package code: PLSP0003ZB-A

(Package name: MPAK)



1. Emitter

2. Base

3. Collector

Note: Marking is "WM-".

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to Base Voltage	V _{CBO}	60	V
Collector to emitter voltage	V _{CEO}	50	V
Emitter to base voltage	V _{EBO}	6	V
Collector current	Ic	1	А
Collector peak current	ic(peak)	2	А
Collector power dissipation	P _C	800*	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

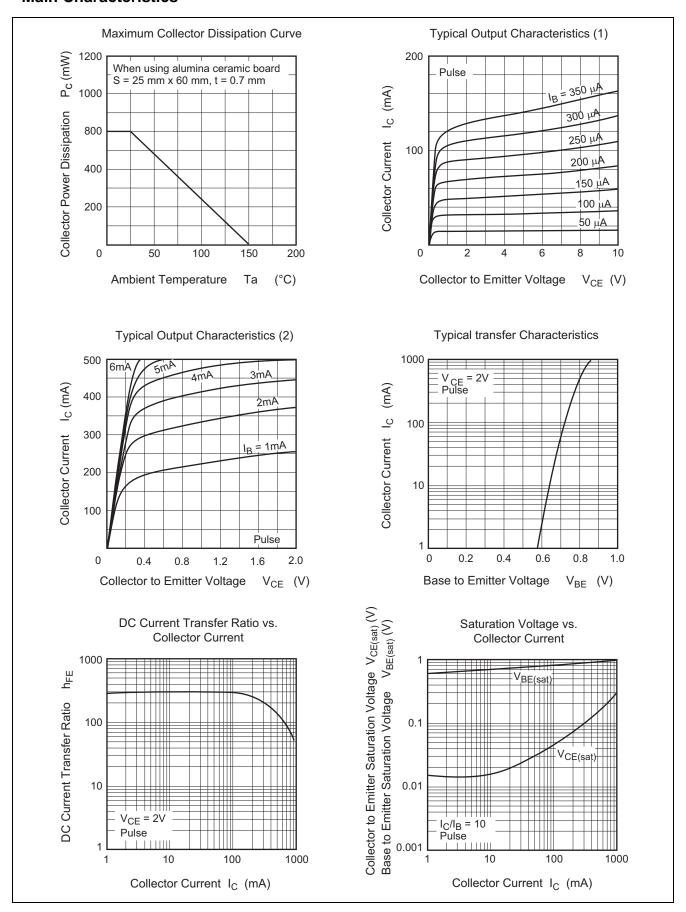
Note: *When using alumina ceramic board (25 x 60 x 0.7 mm)

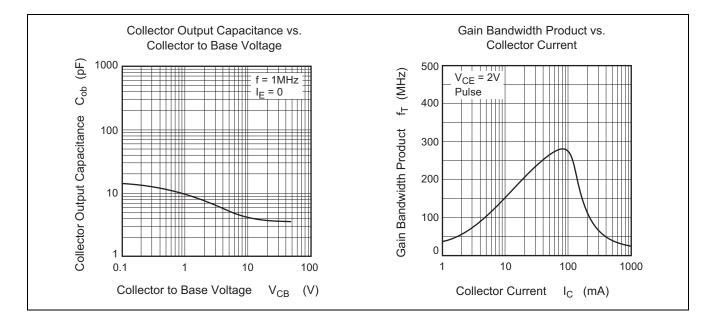
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Collector to base breakdown voltage	$V_{(BR)CBO}$	60	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	50	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	6	_	_	V	$I_E = 10 \mu\text{A}, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	100	nA	$V_{CB} = 50 \text{ V}, I_E = 0$
Emitter cutoff current	I _{EBO}	_	_	100	nA	$V_{EB} = 5 \text{ V}, I_{C} = 0$
DC current transfer ratio	h_FE	200	_	500		$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.16	0.3	>	$I_C = 0.5 \text{ A}, I_B = 0.05 \text{ A},$ Pulse test
Base to emitter saturation voltage	$V_{BE(sat)}$	_	0.91	1.2	٧	$I_C = 0.5 \text{ A}, I_B = 0.05 \text{ A},$ Pulse test
Gain bandwidth product	f⊤	_	280	_	MHz	V _{CE} = 2 V, I _C = 0.1 A
Collector output capacitance	Cob		4.2		pF	$V_{CB} = 10 \text{ V}, I_E = 0,$ f = 1 MHz

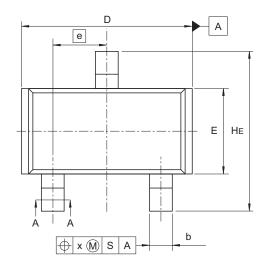
Main Characteristics

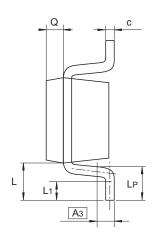


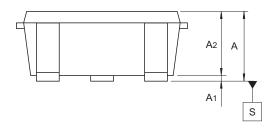


Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011









Reference	Dimensions in millimete		
Symbol	Min	Nom	Max
Α	1.0	_	1.3
A ₁	0	_	0.1
A ₂	1.0	1.1	1.2
A_3		0.25	_
b	0.35	0.4	0.5
С	0.1	0.16	0.26
D	2.7	_	3.1
E	1.35	1.5	1.65
е		0.95	
HE	2.2	2.8	3.0
L	0.35	_	0.75
L ₁	0.15	_	0.55
Lp	0.25	_	0.65
Х	_	_	0.05
Q	_	0.3	_

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Ordering Information

Orderable Part Number	Quantity	Shipping Container
2SD2655WM-TL-E	3000	φ 178 mm Reel, 8 mm Emboss Taping
2SD2655WM-TL-H		

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Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-651-709, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China Tel: +86-10-2325-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 LanGao Rd., Putuo District, Shanghai, China
Tel: +86-21-2226-088, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 161F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

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Renesas Electronics Malaysia Sdn.Bhd.
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Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141

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